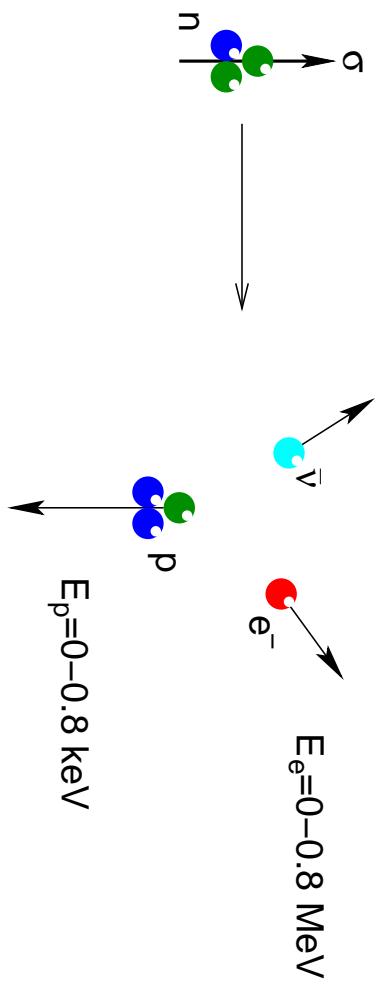


**Measurement of Neutron Beta Decay
Parameters with a Polarized Pulsed Cold
Neutron Beam**

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Los Alamos National Laboratory

Neutron β -Decay



$$\rho(E_e) \approx \rho_s(E_e) \left\{ 1 + P_n [\beta \textcolor{red}{A} \cos \theta_{e\sigma} + \textcolor{red}{B} \cos \theta_{\nu\sigma}] + \beta \textcolor{red}{a} \cos \theta_{e\nu} + \textcolor{red}{b} \frac{m_e}{E_e} \right\}$$

$$A \sim -0.1 \quad B \sim 1 \quad a \sim -0.1 \quad b \sim 0$$

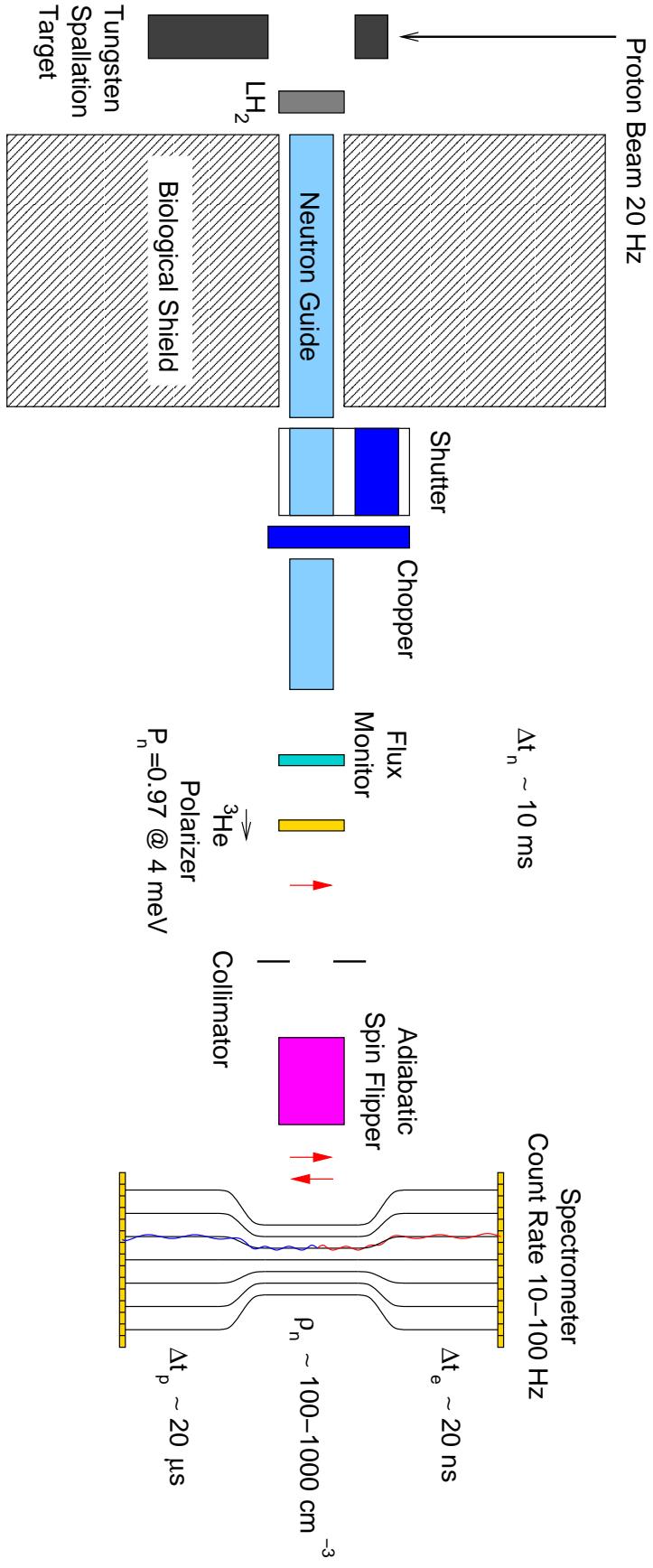
Limitations of Previous Experiments

- Neutron polarization determination
- Backgrounds
- Fiducial volume definition
- Magnetic field pinch
- Scattering from material apertures
- Electron back-scattering
- Detector resolution, efficiency, and stability
- Statistics

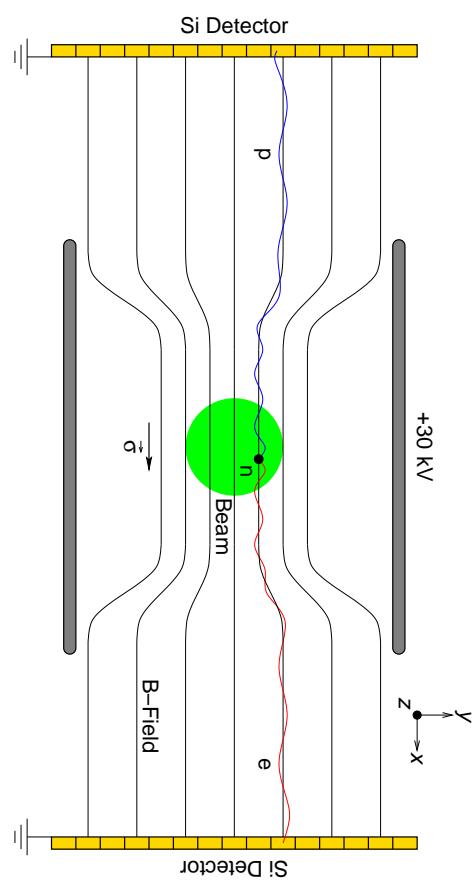
Strategy for LANSCE FP12 Experiment

- *In situ*, absolute neutron polarization measurement
- n , e , and p interact only with B and E fields and detectors
- Fields transport n spin and charged particles adiabatically
- Detect e and p in coincidence
- Measure residual background *in situ* (space and time)
- High-quality detectors: improved ΔE_e , efficiency, stability
- Heavily instrument: do not rely on auxillary calibrations
- Redundancy

Neutron β -Decay with Cold Neutrons at LANSCE



Neutron β -Decay Spectrometer



- Two 2π detectors
- e backscattering monitored
- $\Delta t \sim 1$ ns
- $\Delta E \leq 5$ keV
- $e - p$ coincidence
- Beam imaged by detectors
- *In situ* background measurement
- No material apertures

Neutron Transmission through Polarized ^3He



$$\Phi = \Phi_0 e^{-\sigma x_3} \quad \sigma = \sigma_u \mp P_3(\sigma_s - \sigma_t)/4 = \sigma_u \mp P_3 \sigma_s / 4$$

$$\sigma_s = \sigma_0(v_0/v) \quad \sigma_0 = 54 \text{ barn at 4 meV} \quad v = L/t$$

$$\Phi_+ = \Phi_0 e^{-\sigma_u x_3 + \frac{P_3 x_3 \sigma_0 v_0}{4L} t}$$

$$\Phi_- = \Phi_0 e^{-\sigma_u x_3 - \frac{P_3 x_3 \sigma_0 v_0}{4L} t}$$

Neutron Polarization by Polarized ^3He

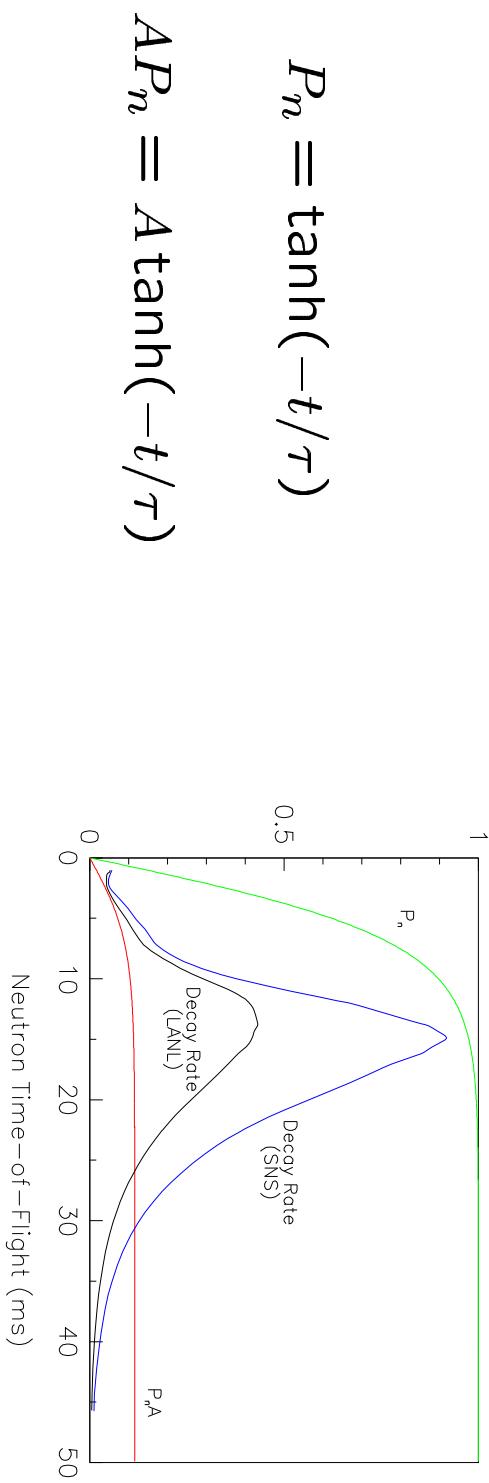
$$P_n = \frac{\phi_+ - \phi_-}{\phi_+ + \phi_-} = \tanh \left(\frac{P_3 x_3 \sigma_0 v_0}{4L} t \right)$$

$$P_n = \tanh(t/\tau)$$

$$\tau = \frac{4L}{P_3 x_3 \sigma_0 v_0}$$

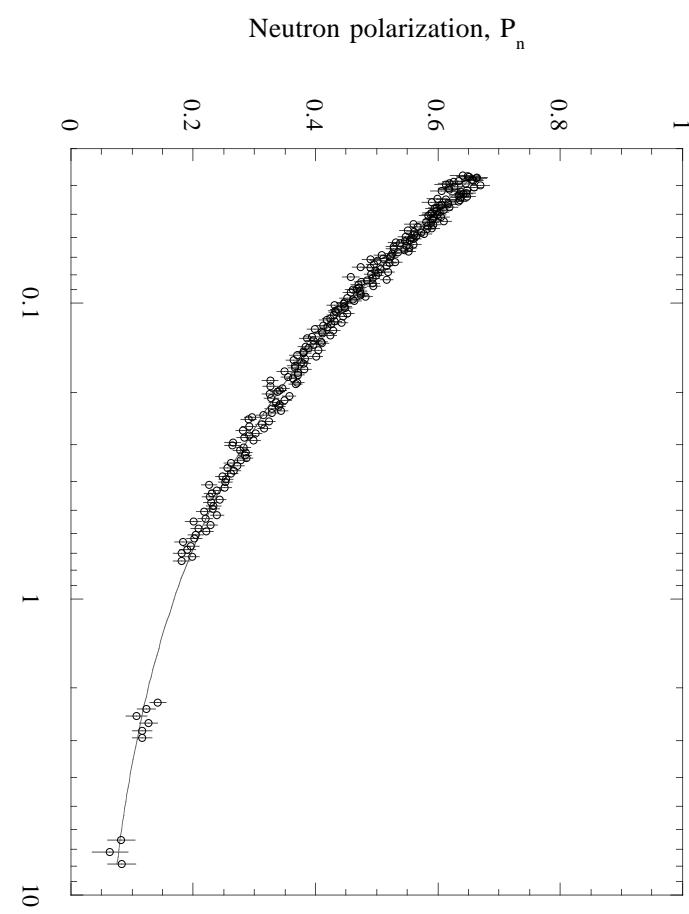
In Situ Polarization Measurement

- Neutrons polarized by transmission through polarized ^3He
- Exact relation between neutron polarization and TOF
- Determine A and τ from $P_n A$



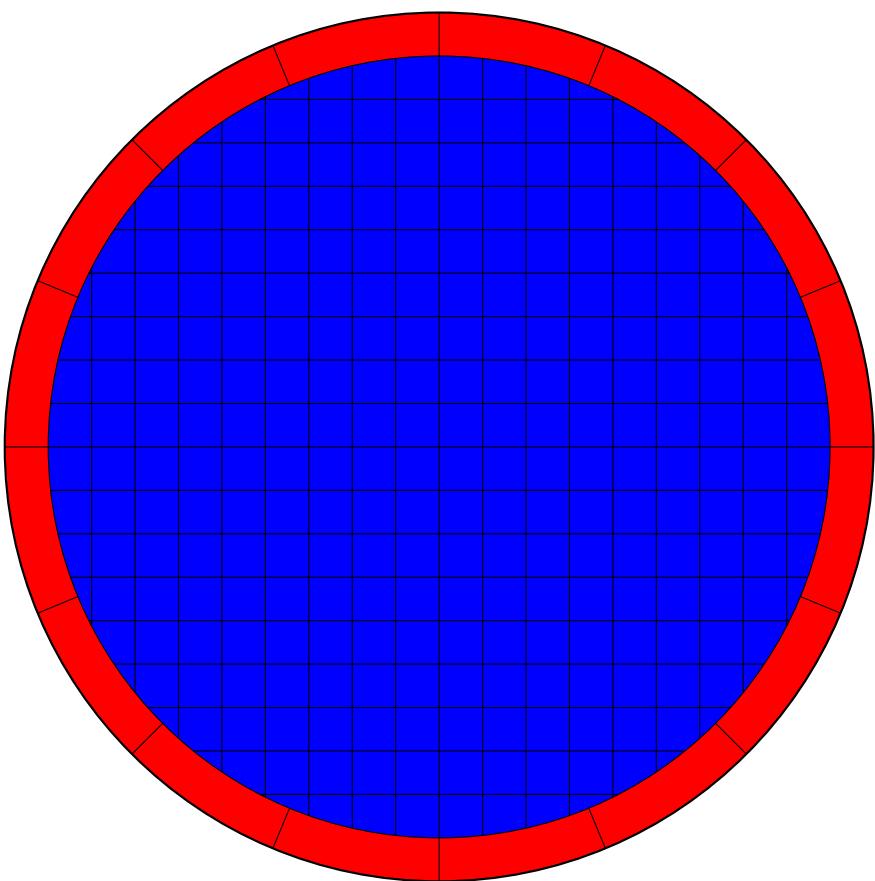
Absolute Neutron Polarimetry at LANSCE

$$\Delta P_n \leq 0.2\%$$



D.R. Rich, et al. Nucl. Instr. Meth., In press.

Detector Design



13 cm Diameter, 2 mm Thick Silicon Wafer, 100 Channel

Prototype Detector

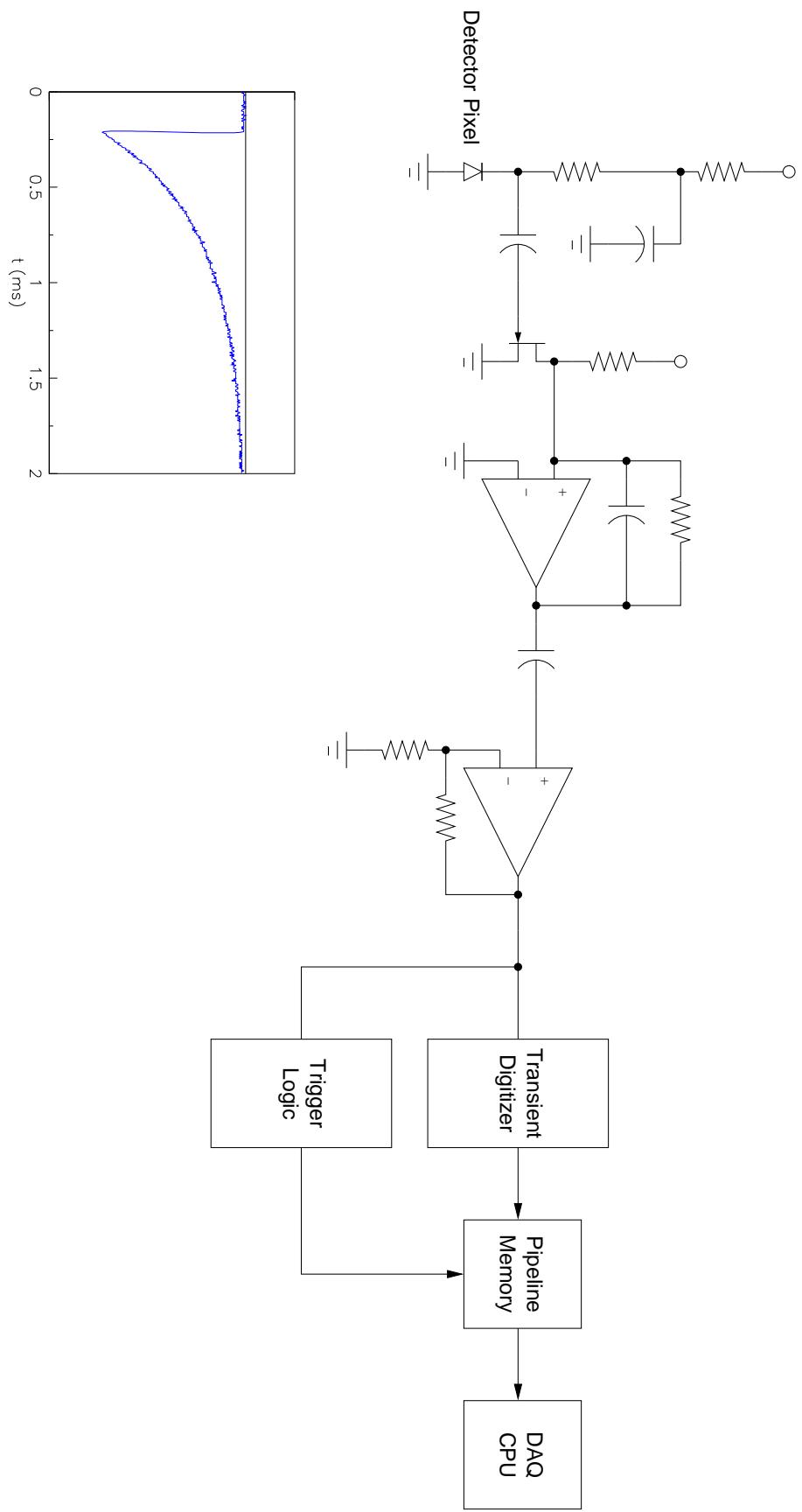


5 × 5 cm², 1.5 mm Thick Silicon, 16 Channel

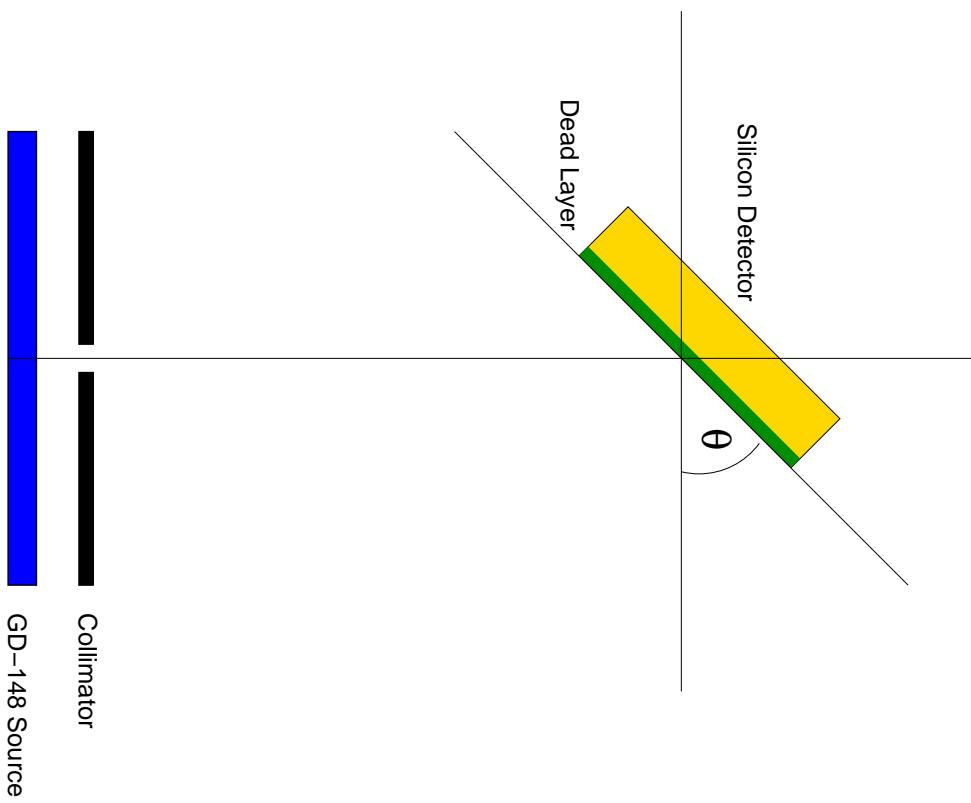
Advantages of Silicon Detectors

- Thin dead layer: $\Delta E_e \leq 5 \text{ eV}$, $\Delta E_p \leq 5 \text{ keV}$ measured
- Almost unity efficiency: small well-understood corrections
- Extremely uniform dead layer: no wires, foils, supports, etc.
- 4π detection of electrons and protons: coincidence
- Imaging: defines fiducial volume without material apertures, provides *in situ* background measurement

Detector Electronics

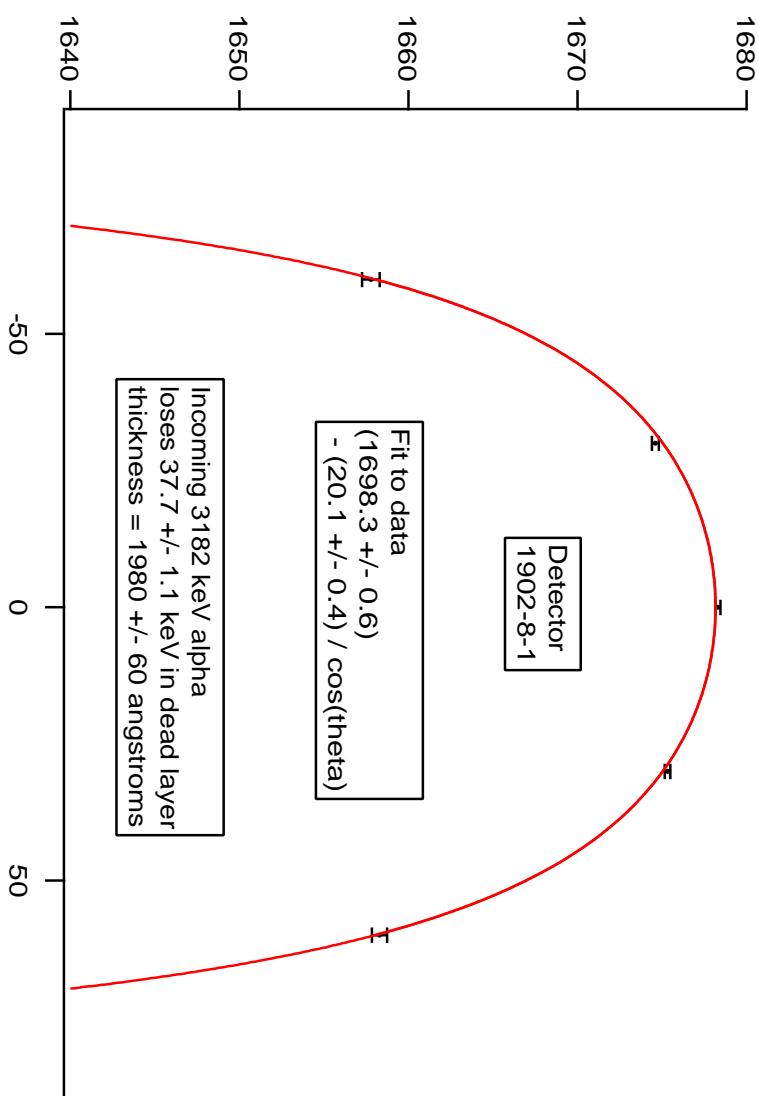


Dead Layer Measurements



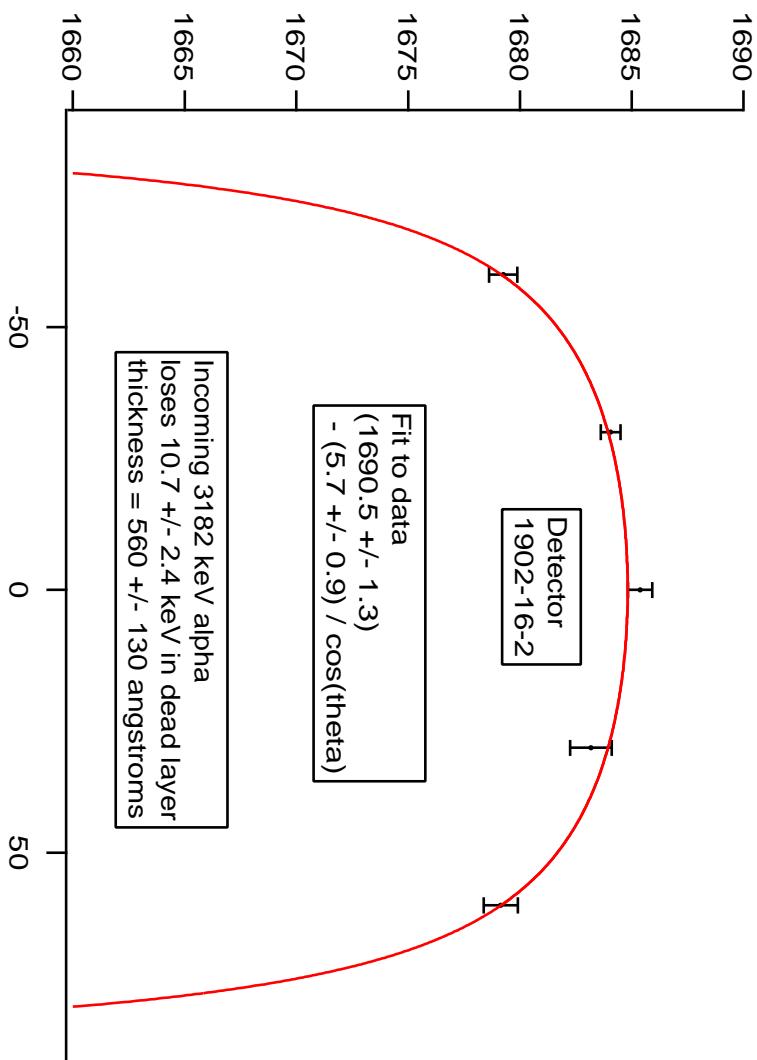
Collimator
GD-148 Source

Normal Silicon Detector



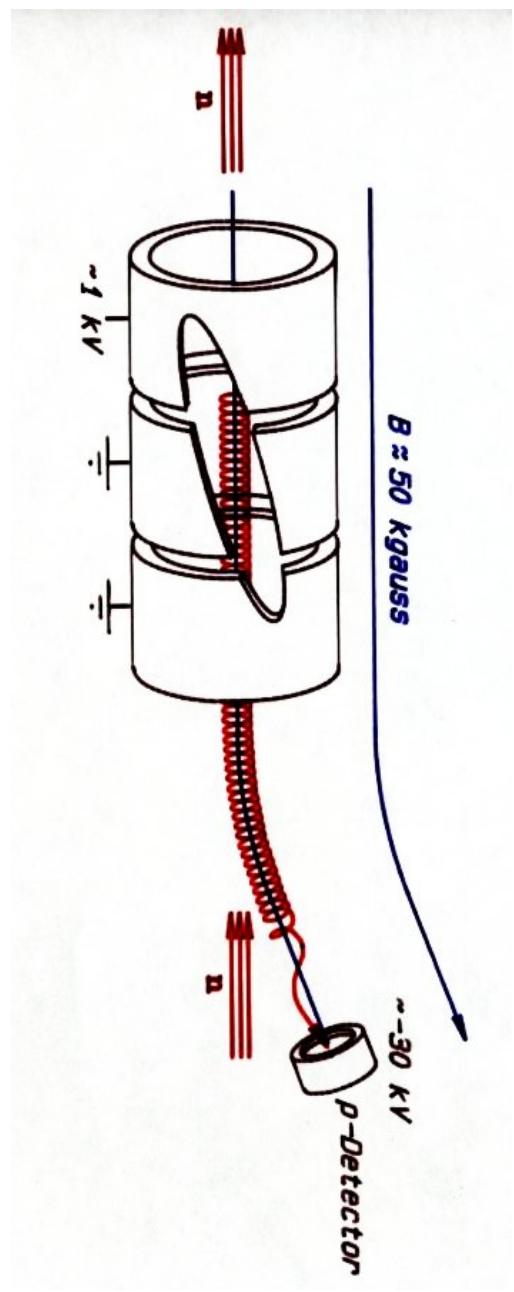
200 nm Dead Layer
 $E_{\text{loss}} = 14 \text{ keV}$ for $E_p = 30 \text{ keV}$

Thin Dead Layer Silicon Detector



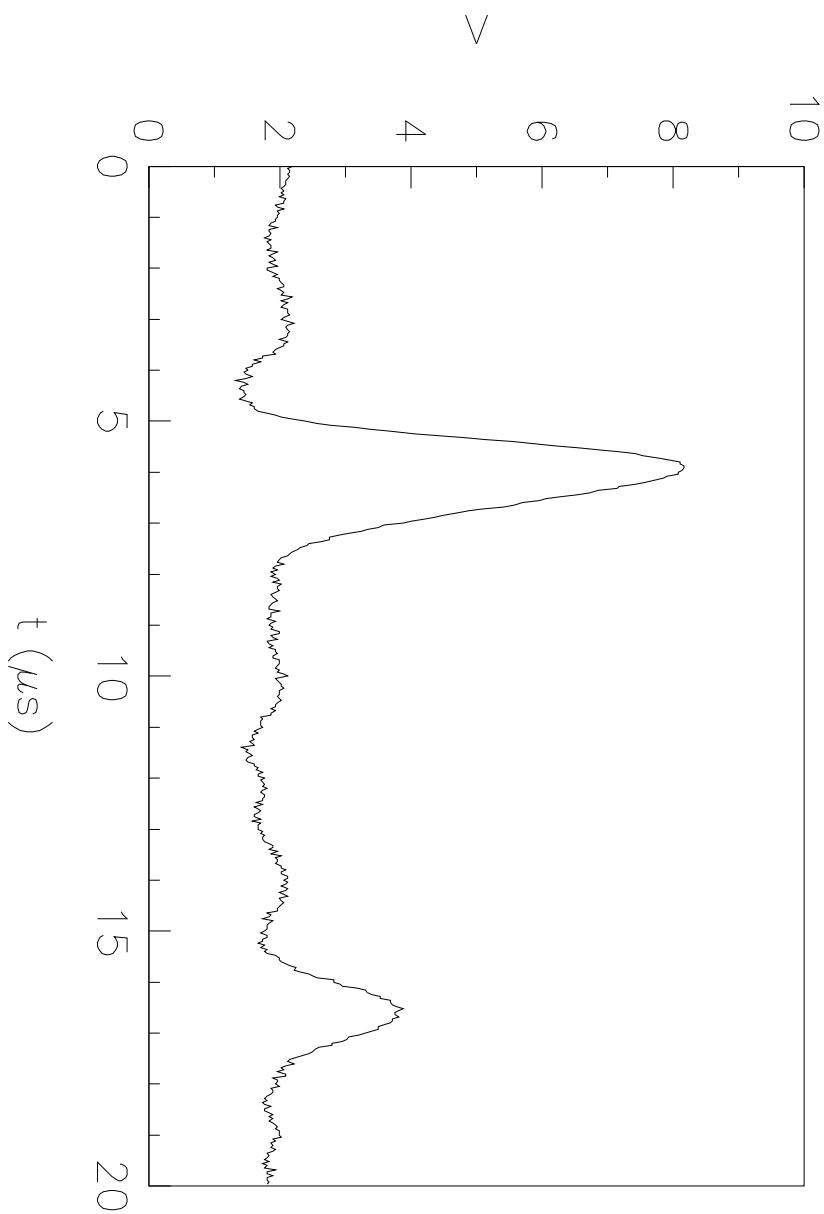
56 nm Dead Layer
 $E_{\text{loss}} = 5$ keV for $E_p = 30$ keV

Silicon Detector Tests at NIST



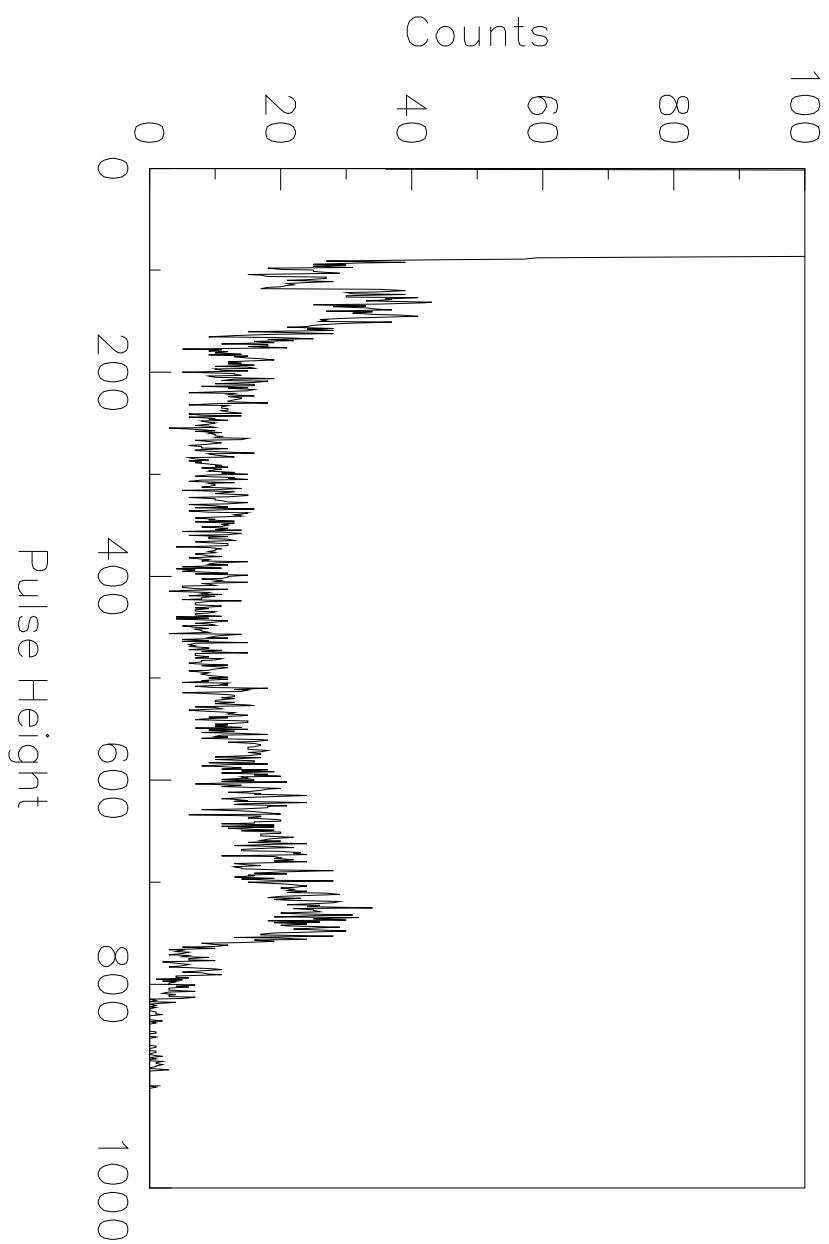
- Neutrons decay in magnetic solenoid
- Charge particles guided to detector by magnetic field
- Protons accelerated to 30 keV

Electron-Proton Coincidence



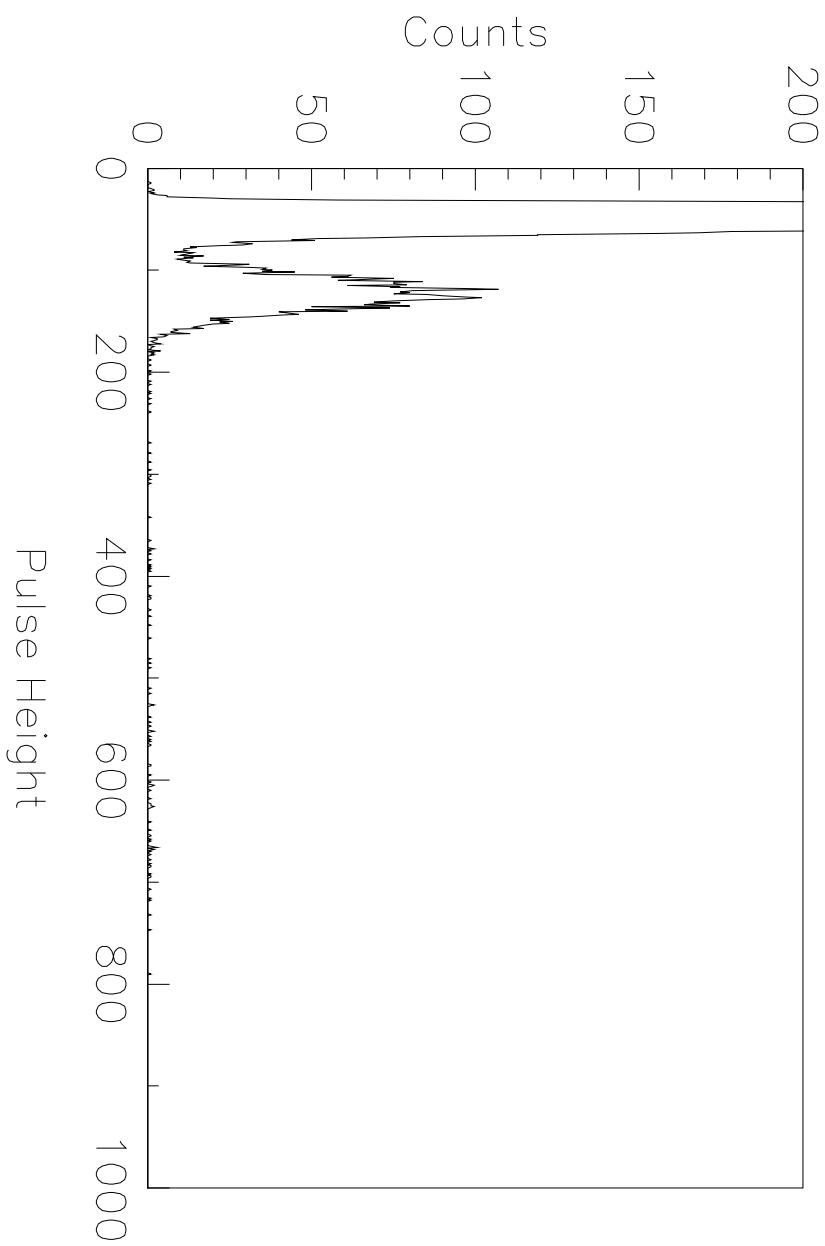
e and *p* seen in same detector

Neutron Decay Spectrum



No Coincidence

Neutron Decay Spectrum



e – p Coincidence

Footprint of Experiment

